

Magnetoelectric phase diagrams of multiferroic GdMn_2O_5

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Electric and magnetic properties of multiferroic GdMn_2O_5 in external magnetic fields were investigated to map out the magnetoelectric phases in this material. Due to strong magnetoelectric coupling, the dielectric permittivity is highly sensitive to phase boundaries in GdMn_2O_5 , which allowed us to construct the field-temperature phase diagrams. Several phase transitions are observed which are strongly field dependent with respect to field orientation and strength. The phase diagram for a magnetic field along the crystallographic a axis corresponds well to a polarization step, as induced by 90° rotation of Gd magnetic moments. Our results support the model of two ferroelectric sublattices, Mn-Mn and Gd-Mn, with strong R -Mn ($4f$ - $3d$) interaction for the polarization in RMn_2O_5 .

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I. INTRODUCTION

Multiferroics are materials in which magnetic and electric orders coexist and which are promising for the development of novel functional materials and devices [1–4]. The coupling between the magnetic and electric degrees of freedom has the consequence that multiferroics exhibit new physical effects: electric and magnetic orders can be modified by external magnetic or electric fields and the propagation of electromagnetic radiation can be controlled.

Recently, the observation of large polarization [5] in GdMn_2O_5 and of colossal magnetoelectric effect in TbMn_2O_5 and DyMn_2O_5 had a significant impact in the field of multiferroics [6,7]. Rare-earth multiferroic manganites RMn_2O_5 received much attention because of large ferroelectric polarization, puzzling magnetic structure, and strong coupling between magnetic and ferroelectric orders [5–7], as compared to other multiferroics such as RMnO_3 [8,9], LiCu_2O_2 [10], and MnWO_4 [11,12]. Because of the complex magnetic interactions and spin-lattice coupling, our current understanding of the underlying physics in RMn_2O_5 still needs considerable efforts [13,14].

A. RMn_2O_5

RMn_2O_5 has an orthorhombic crystal structure with $Pbam$ space group at room temperature [15,16] as exemplified in Fig. 1 for GdMn_2O_5 . The complex magnetism in this system originates from the $3d$ magnetic moments of Mn^{3+} , Mn^{4+} and from the $4f$ magnetic moment of R^{3+} . There exist five relevant magnetic interactions between neighboring spins, which makes the system highly frustrated and gives rise to various magnetically ordered phases with long-period modulation wavelength [17]. Due to inherent magnetic frustration below the Néel temperature $T_{N1} \sim 40$ K, RMn_2O_5 shows a cascade of successive phase transitions upon temperature variation. In most members of the RMn_2O_5 family, common phase transitions occur below T_{N1} , such as the high temperature

incommensurate magnetic (HT-ICM) phase characterized by wave vector $\mathbf{q} = (q_x, 0, q_z)$, and a lock-in transition from HT-ICM to the commensurate magnetic (CM) phase with $\mathbf{q} = (1/2, 0, 1/4)$, where ferroelectric polarization arises. On further cooling, the CM phase is destroyed and a new low temperature incommensurate (LT-ICM) phase may emerge. Moreover, in some cases, another phase appears between the HT-ICM and CM, known as the one-dimensional incommensurate (1D-ICM) phase [17].

B. GdMn_2O_5

The magnetic structure of GdMn_2O_5 is slightly different from other members of the RMn_2O_5 family. Lee *et al.* show [5] that an incommensurate phase occurs below $T_{N1} \sim 40$ K with a wave vector $\mathbf{q} = (0.486, 0, 0.18)$, followed by a commensurate phase with $\mathbf{q} = (1/2, 0, 0)$ below $T_{N2} \sim 31$ K, which does not change further at low temperatures. This sequence of the wave vectors is due to the active involvement of Gd ions below $T_C \sim 29$ K because of their large atomic radius and high magnetic moments. This structure leads to tunable ferroelectricity in GdMn_2O_5 in external magnetic fields [18,19], inducing a giant change of polarization by $\sim 5000 \mu\text{C}/\text{m}^2$, the largest among the known multiferroic systems [5]. Recently, pressure-induced change in the polarization at the ferroelectric transition in GdMn_2O_5 has been observed and attributed to Gd-Mn decoupling at high pressure due to lattice contraction [20,21].

In RMn_2O_5 multiferroics, there exists strong coupling between electric polarization and magnetic order. The polarization can be induced by an applied magnetic field in HoMn_2O_5 and DyMn_2O_5 [7,22,23], suppressed in ErMn_2O_5 [22], reversed in TbMn_2O_5 [6] and GdMn_2O_5 [5], or flopped in TmMn_2O_5 [24] and YbMn_2O_5 [25]. These effects are observed in the low-temperature magnetically ordered phases. Recently, the magnetic field effect on the electric polarization has been demonstrated in the NdMn_2O_5 multiferroic [26].

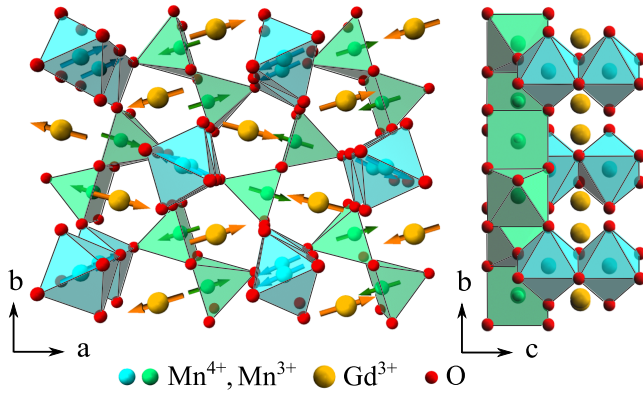


FIG. 1. Crystallographic structure of GdMn_2O_5 in the commensurate magnetically ordered state. Chains of light blue octahedra containing Mn^{4+} ions run along the c axis. Mn^{3+} are located inside the green square pyramids alternating with Gd^{3+} in every second a - b plane. Arrows indicate the spin orientations in the low-field low-temperature phase.

In RMn_2O_5 , the dielectric response in the external magnetic field depends strongly on the type of rare earth and the direction of applied field. It has been found that magnetic fields affect the low temperature region (below ~ 25 K), leading to remarkable magnetoelectric response. It indicates the key role of the $4f$ moments of the rare-earth ions in interaction with the external field which exists even at higher temperatures.

In this work we present a set of dielectric properties $\varepsilon(H, T)$ along the crystallographic axes a, b , and c and in external magnetic fields. From the observed dielectric anomalies, we construct the magnetoelectric phase diagrams of GdMn_2O_5 . Taking into account the results of previous studies, an assignment of various phases is suggested.

II. EXPERIMENT

Dielectric and magnetic properties of single crystalline GdMn_2O_5 have been measured in magnetic fields up to 12 T and at temperatures between 2 and 60 K using the Physical Property Measurement System. The system was supplemented by the vibrating magnetometer and by the Alpha impedance analyzer to measure the complex dielectric permittivity ε . Dielectric results shown originate from measurements at fixed frequency of 10 kHz.

The single crystal of GdMn_2O_5 was grown by using the flux method [5,6], similar to other RMn_2O_5 compounds. After determining the orientation of axes by Laue diffraction, it was cut into plane-parallel slices of area $\sim 5 \times 5$ mm² and thickness ~ 0.5 mm normal to the crystallographic c axis. To obtain samples of other orientations, the slice dedicated for dielectric experiments was cut into several rectangular pieces parallel to the a and b axes. Dielectric experiments on samples with ac electric field $E \parallel a, b$ were performed on mosaic samples assembled from about five such fragments and fixed with GE-varnish. Spontaneous electric polarization has been measured on a small crystal of about $0.4 \times 0.4 \times 0.4$ mm³ in size. To obtain initial information on the characteristic temperatures and magnetic fields in GdMn_2O_5 , additional dielectric experiments were carried out using polycrystalline

samples. Electric contacts to the samples were produced using silver paste. The temperature scans of dielectric permittivity between 2 and 60 K were done under several fixed magnetic fields $\mu_0 H$, up to 12 T. Sweeping the magnetic field at selected temperatures provided additional information to complete the magnetoelectric phase diagrams.

In dielectric and magnetoelectric experiments, it is important to take care of possible artifacts due to conductivity [27] and magnetoresistance [28,29] in the sample. In order to exclude such effects, several test experiments at different frequencies were carried out. We found that the real part of the dielectric permittivity ε_1 , measured at frequencies of 1, 10, and 100 kHz, agree with each other within a few percent. In addition, the imaginary part of the permittivity ε_2 does not exceed ~ 0.2 in all experiments below $T = 70$ K. We believe that these tests exclude extrinsic conducting effects in our measurements. Such effects could indeed be observed at temperatures above 100 K as $\sim 50\%$ increase of ε_1 and as ε_2 increasing by factor of 3.

III. RESULTS

Figure 2 shows the temperature dependence of the dielectric permittivity along the a, b , and c axes in a range of magnetic fields (0–12 T), parallel to all three axes. The upper panels show the experiments in zero magnetic field on a small crystal. The lower panels show the results of the experiments in external magnetic field on a mosaic sample. The sample holder for external fields did not allow the absolute measurements due to a large stray signal. On cooling from the paramagnetic state, the dielectric permittivity starts to increase below ~ 40 K in zero magnetic field, which is the onset of long range incommensurate antiferromagnetic (ICM) order at $T_{N1} \sim 39$ K. By further cooling, ε exhibits a kink at $T_{N2} \sim 31$ K and a peak at $T_C \sim 29$ K, where the static polarization [5,20] along the b -axis ($P \parallel b$) appears (see Fig. 3). This ferroelectric state for $T < T_{N2}$ coincides with a commensurate magnetic order [5] with $\mathbf{q} = (1/2, 0, 0)$. In contrast to other RMn_2O_5 , GdMn_2O_5 reveals two close ferroelectric transitions at T_{N2} and T_C , respectively.

Near $T_C \sim 29$ K, the dielectric permittivity exhibits a divergent behavior identifying a ferroelectric phase transition accompanied by a rapid growth of $P \parallel b$. Additionally, a small anomaly at low temperatures appears at $T \sim 12$ K. Since this temperature closely coincides with a maximum of the magnetic susceptibility along the a axis (see Fig. 6), we attribute this anomaly to Gd ordering transition [5,18,30].

For several other members of the RMn_2O_5 family, the main ferroelectric peak is nearly independent of the applied field [7,22]. One of the interesting consequences of external magnetic fields in GdMn_2O_5 is the transformation of the kink at T_{N2} into a well pronounced peak which further moves towards higher temperatures with increasing magnetic field $\mu_0 H_a > 3$ T. In addition, the sharp peak at T_C decreases rapidly and moves towards lower temperatures with increasing H_a and fully vanishes at $\mu_0 H_a \sim 6$ T. In the geometry $H \parallel a$, a new peak appears in the low temperature range at $T_{X2} \sim 20$ K, above 6 T. This temperature separates two ferroelectric phases assigned as FE1 and FE5 (see Fig. 4).

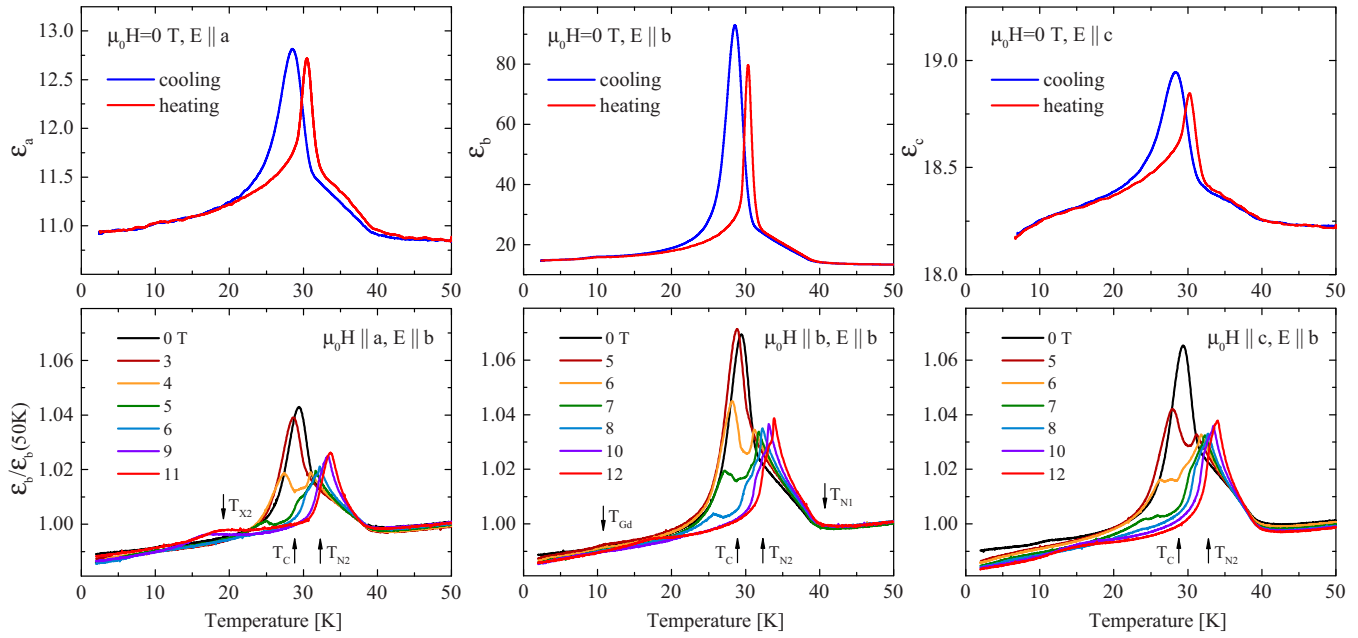


FIG. 2. Upper panels: Temperature dependent dielectric permittivity ε_a , ε_b , and ε_c for GdMn_2O_5 in zero magnetic field as obtained on a small single crystal. $E \parallel a, b, c$ is the ac electric field. Lower panels: Experiments in external magnetic fields up to $\mu_0 H = 12$ T along three crystallographic axes, as measured on a mosaic sample. The measurements were recorded on cooling run. The arrows indicate the temperatures of the phase transitions.

Applying magnetic fields along the b and c axes, qualitatively similar dependencies are observed (Fig. 2), except for substantially higher absolute values of the characteristic fields at the phase transitions. This agrees well with the fact that the a axis is the easy magnetic axis.

The results of the static polarization experiments on a small GdMn_2O_5 crystal are shown in Fig. 3. The left panel of Fig. 3 shows the data for the zero magnetic field and it demonstrates that static polarization in GdMn_2O_5 can be seen solely along the b axis in the zero magnetic field. We note that spontaneous polarization shows a well-defined step and substantial hysteresis at T_C . Both features are indications of the first-order transition in GdMn_2O_5 . As may be expected from the results of dielectric experiments, several additional phase transitions are observed in electric polarization of GdMn_2O_5 in external magnetic fields. The splitting of the ferroelectric

transition at $T_C \sim 29$ K is visible as complex behavior of the polarization around this temperature. In high magnetic fields (middle panel) $\mu_0 H \geq 6$ T, the saturation tendency of $P_b \rightarrow 1500 \mu\text{C}/\text{m}^2$ below T_C is interrupted close to $T_{X2} \sim 20$ K and an additional contribution to the polarization starts to grow. As a result, the low-temperature polarization in GdMn_2O_5 reaches $P_b \sim 2500 \mu\text{C}/\text{m}^2$. As will be discussed below, we attribute an additional contribution to the influence of Mn-Gd interactions.

Another interesting result of the polarization experiments is the appearance of a sharp steplike feature in P_b at $T_p \sim 5$ K in the field range of 4.5–5.5 T which is marked by arrows in the middle and right panels of Fig. 3. This feature is accompanied by a peak in the dielectric permittivity at the same temperature. The behavior of electric polarization around T_p may be a hint for a possible partial polarization flop from the $P \parallel b$ axis to the a or c axes. Similar polarization flops occurring

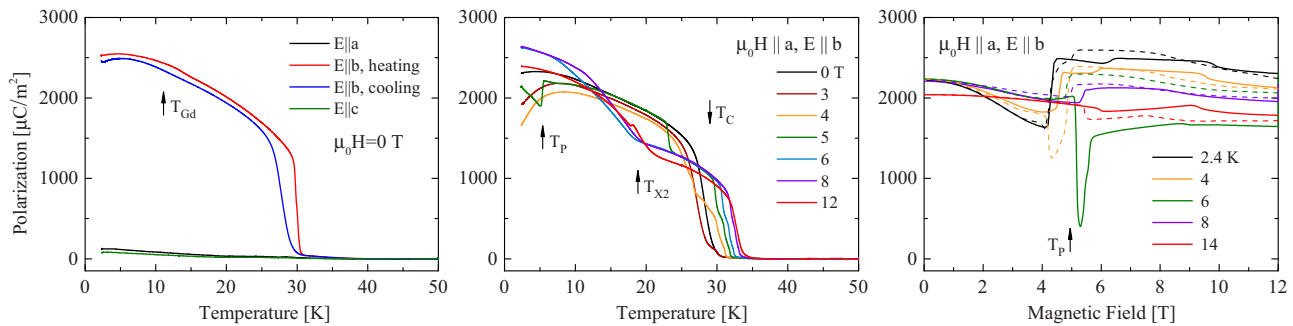


FIG. 3. Spontaneous electric polarization in GdMn_2O_5 . Left panel: Polarization in zero magnetic field for three crystallographic directions as indicated. Middle panel: Electric polarization along the b axis in the external magnetic field $H \parallel a$ axis, measured on cooling run. Right panel: Magnetic field dependence of the polarization at different temperatures. Solid lines: increasing field, dashed lines: decreasing field. Positions of the phase transitions are marked by arrows.

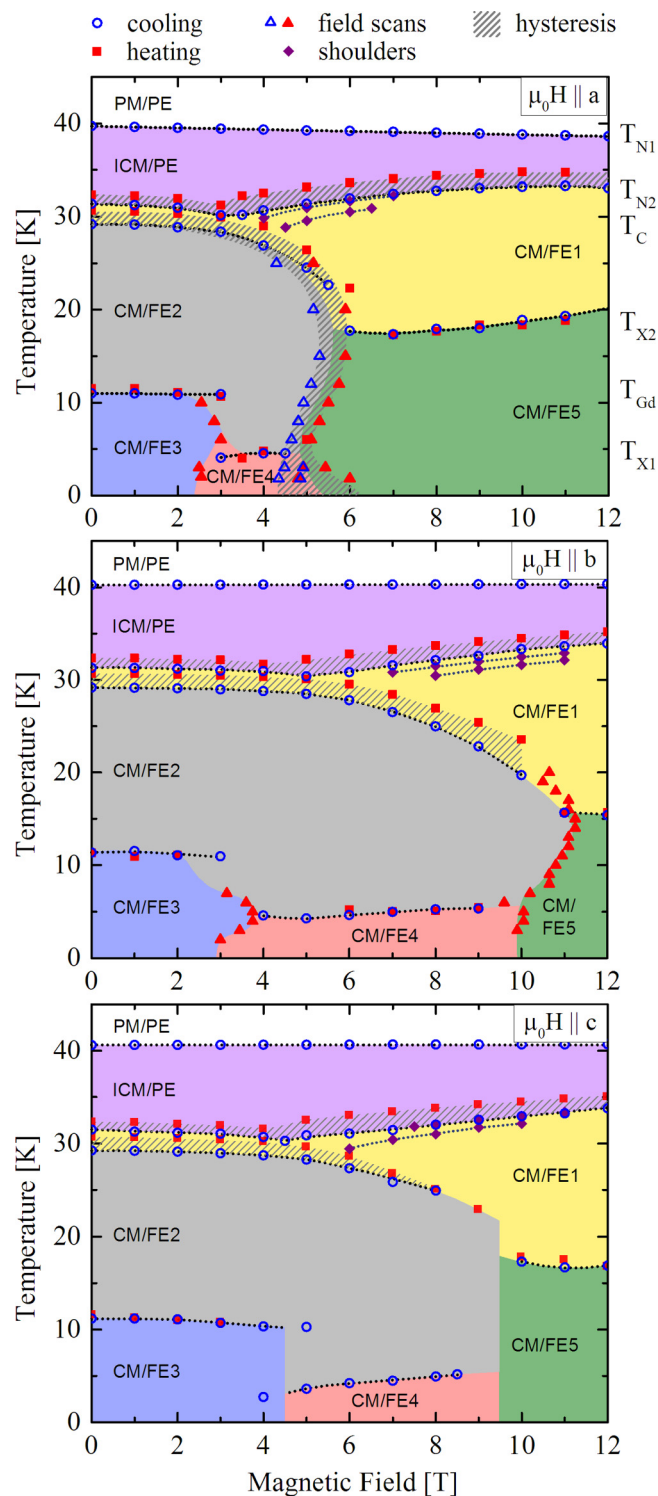


FIG. 4. Magnetolectric phase diagrams of GdMn_2O_5 with magnetic field along the a , b , and c axes. Open circles and closed squares represent the data obtained with decreasing and increasing temperature, respectively. Open and closed triangles denote the data obtained in magnetic field sweep in increasing and decreasing fields, respectively. Shaded regions show the hysteresis effects.

at ~ 5 K in external magnetic fields have been observed earlier in YbMn_2O_5 [25] and in TmMn_2O_5 [24]. However, in the present experiments no spontaneous polarization along

the a or c axes could be observed within the experimental accuracy.

Summarizing our experimental results on electric and magnetic properties of GdMn_2O_5 , we show the magnetolectric phase diagrams for external magnetic fields along the a , b , and c axes, as shown in Fig. 4. The two phase boundaries defined by T_{N1} and T_{N2} in the phase diagram, are similar for external magnetic fields along all axes. These phase boundaries correspond to the phase transitions $\text{PM/PE} \rightarrow \text{ICM/PE}$ at T_{N1} and $\text{ICM/PE} \rightarrow \text{CM/FE1}$ at T_{N2} . The phase boundaries of T_{N2} and T_C show a strong hysteresis effect indicating the first-order transition [22].

To support the determination of the phase boundaries, magnetic field scans of the dielectric permittivity $\varepsilon(H)$ below 40 K and in the fields up to $\mu_0 H = 12$ T were performed and are shown in Fig. 5. For $H \parallel a$ and $E \parallel b$ (top left), in varying fields and at low temperatures $T \leq 10$ K, an anomaly has been identified around 3 T, which coincides with the phase boundary drawn from temperature scans. With increasing fields up to 6 T (top right), a clear jumplike anomaly is evident below ~ 18 K, which coincides with the Gd spin-flop transition [5]. This phase boundary is only weakly temperature dependent and, therefore, it has not been observed in fixed-field scans. For $H \parallel b$ and $E \parallel a$ (bottom right), strong anomalies of $\varepsilon_a(H)$ around 11 T have been detected, which corresponds to the same phase boundary in the $H \parallel b$ geometry.

In the case of $H \parallel a$, the boundary at T_C between the FE2 and FE1 phases smoothly transforms to the FE2/FE5 phase boundary around 5.5 T. At low temperatures ($T < 6$ K), additional structure is seen in several magnetic field-dependent experiments. Because this temperature range corresponds to an ordered state of the Gd spins, a possible explanation for additional boundaries may be a reorientation of the Gd sublattice. As mentioned above, a clear peak in ε_a has been observed at this boundary.

We recall that in magnetic field-dependent experiments (Fig. 5), several steplike features have been observed in GdMn_2O_5 . According to the sum rule for the static dielectric permittivity [31], an electrically dipole-active excitation may then be suggested to exist at high frequencies. Similar to electromagnons in several multiferroics [32,33], a step in the dielectric permittivity may directly correspond to a change in dielectric contribution of a high-frequency mode.

In order to complete the magnetolectric phase diagram, magnetization measurements in GdMn_2O_5 have been carried out in several magnetic fields along the a axis, as shown in Fig. 6. The paramagnetic susceptibility above $T_{N1} \sim 39$ K approximately follows the Curie-Weiss law $M/H \sim 1/(T + \theta)$ with θ around 25 K. The Néel transition temperature is seen in the magnetization data after subtraction of a smooth function of temperature, which is shown in the insets of Fig. 6. One prominent feature in the low-field magnetization is a broad maximum around $T_{\text{Gd}} \sim 12$ K which is attributed to the ordering of the Gd subsystem. A steplike feature at $\mu_0 H = 5$ T and around 8 K probably corresponds to the spin-flop transition of Gd ions. This transition is clearly seen in the field-dependent magnetization curves until $T = 30$ K (not shown), suggesting the existence of Gd order in both high-field phases, FE1 and FE5.

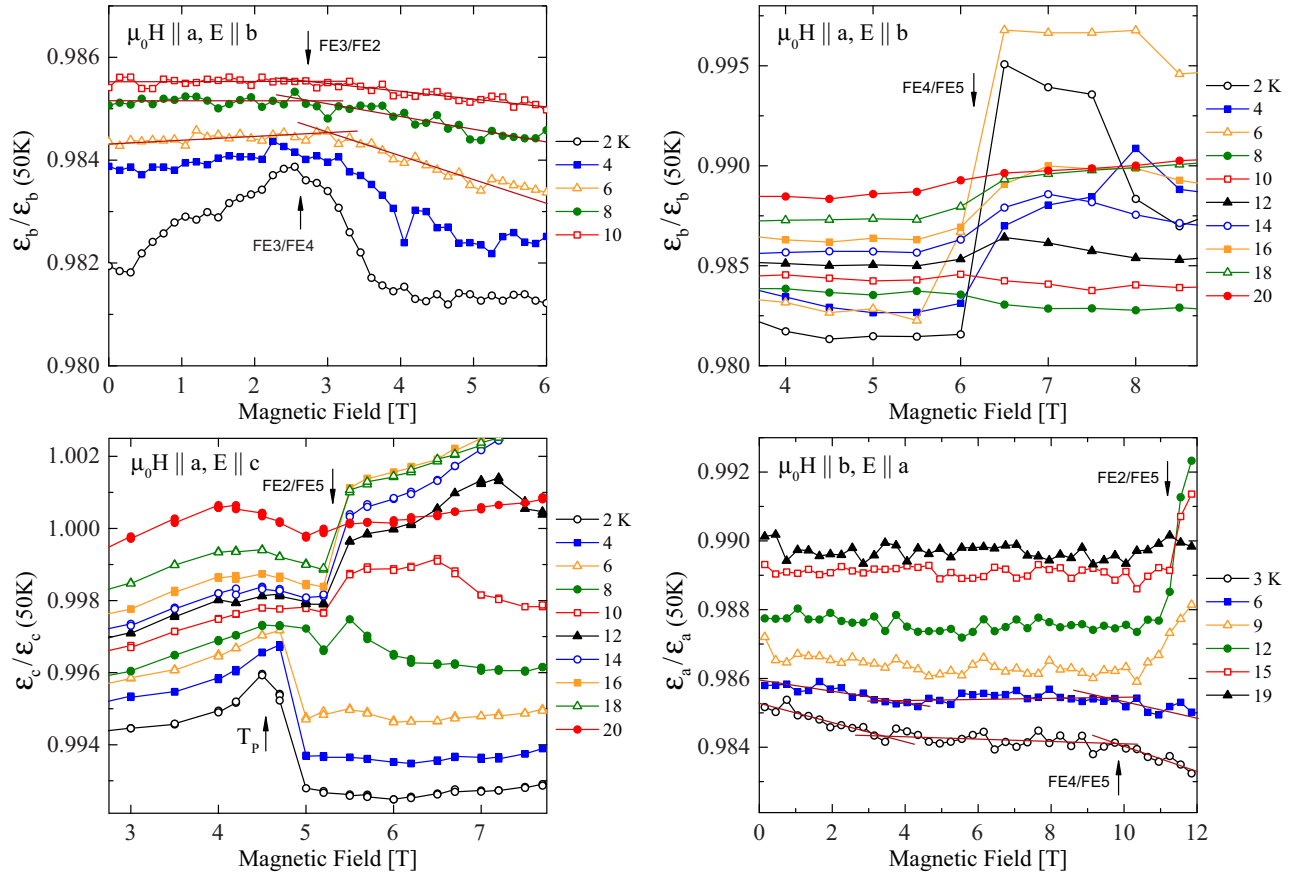


FIG. 5. Example of magnetic field dependence of dielectric permittivity in GdMn_2O_5 at various temperatures. Straight red lines show the positions of changes-in-slope in $\varepsilon(H)$. Arrows indicate the suggested field values at the phase boundaries.

The phase diagrams for $H \parallel b$ and $H \parallel c$ exhibit similar phase sequences as observed for $H \parallel a$, despite of the difference in

absolute values of critical fields. Therefore, we suggest that fundamental physics in the different phases (FE1 \rightarrow FE5) is the same in all GdMn_2O_5 phase diagrams.

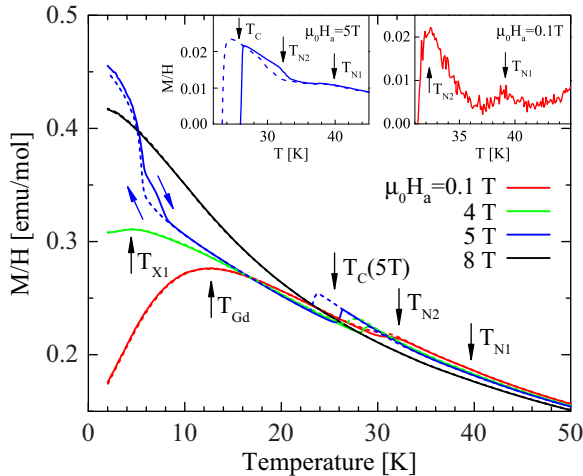


FIG. 6. Temperature dependence of the magnetization in GdMn_2O_5 along the easy axis and at several external fields, as indicated. All main phase transitions are well seen in the magnetic data. Left and right insets show the magnetization at $\mu_0 H_a = 5 \text{ T}$ and at $\mu_0 H_a = 0.1 \text{ T}$, respectively, with smooth background subtracted to reveal the magnetic transition temperatures T_{N1} and T_{N2} . Arrows indicate the transition temperatures between different magnetic phases.

IV. DISCUSSION

The series of the magnetoelectric transitions presented here is in agreement with previous experiments in GdMn_2O_5 [5,20,21]. Figure 7 reproduces the main features of the phase diagram in Fig. 4 (for $H \parallel a$) and of the field-dependent polarization given in Fig. 3. The polarization data are given as color scale and they fit well in the magnetoelectric phase diagram.

Following the arguments of Lee *et al.* [5], the boundary around 5.5 T between the FE2 and FE5 phases corresponds to a switching of additional mechanisms of electric polarization in GdMn_2O_5 . The total electric polarization may be obtained as a competition of two contributions originating from the symmetric exchange-striction mechanism in Mn-Mn and Mn-Gd spin subsystems, respectively. In magnetic fields exceeding $\mu_0 H_a \sim 5.5 \text{ T}$, the Gd spins rotate by 90° leading to the inversion of the Mn-Gd contribution to electric polarization. As a result, the total polarization in the right panel of Fig. 3 increases from $P_b(4\text{T})$ (FE4) $\sim 1500 \mu\text{C}/\text{m}^2$ to about $P_b(8\text{T})$ (FE5) $\sim 2500 \mu\text{C}/\text{m}^2$.

Magnetic field dependence of the electric polarization in Fig. 3 is rather complex. Remarkable is a sharp decrease

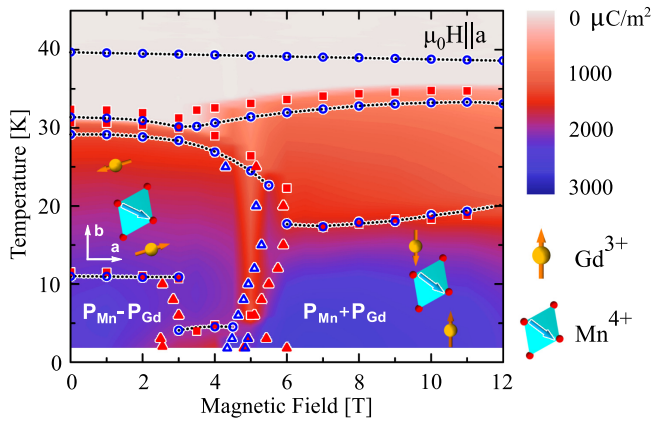


FIG. 7. Color-coded magnetoelectric phase diagram of GdMn_2O_5 in the $H\parallel a$ geometry, as obtained from the interpolation of the polarization data of Fig. 3. Relative orientation of Mn and Gd moments are given as pictograms illustrating the suggested 90° rotation of Gd spins.

of P_b at fields ~ 5 T, which is followed by a steplike increase for further increasing fields. Conversely, in previous experiments [5] only a decrease of electric polarization has been observed reaching even negative values and remaining

stable until $B = 9$ T. Most probably, the complex magnetic structure of GdMn_2O_5 is sensitive to the exact orientation of the external field and to details of cooling and poling procedures. Further investigations are necessary to resolve this problem.

V. CONCLUSIONS

Magnetodielectric effects for single crystalline GdMn_2O_5 have been investigated using dielectric spectroscopy, electric polarizations, and magnetic experiments. Several phase transitions are observed which are strongly field dependent with respect to field orientation and strength. A full set of magnetoelectric phase diagrams in external magnetic fields has been determined. Qualitative similarity of the phase diagrams suggests that the same sequence of magnetoelectric phases exists for all geometries in GdMn_2O_5 .

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